

SHINDENGEN

Schottky Rectifiers (SBD)

Dual

DF30SC4M

40V 30A

FEATURES

- SMT
- $T_j=150^\circ\text{C}$
- V_{RRSM} avalanche guaranteed
- High current capacity with Small Package

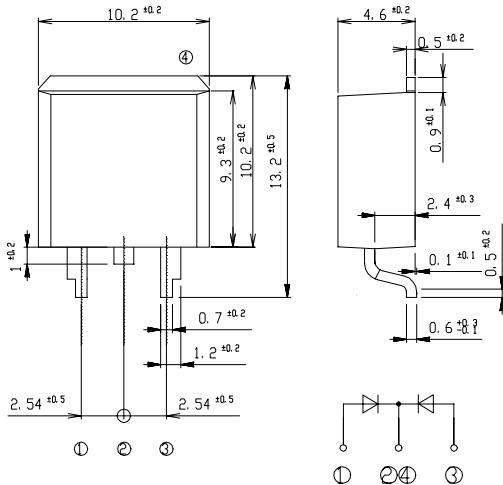
APPLICATION

- Switching power supply
- DC/DC converter
- Home Appliances, Office Equipment
- Telecommunication

OUTLINE DIMENSIONS

Case : STO-220

Unit : mm



RATINGS

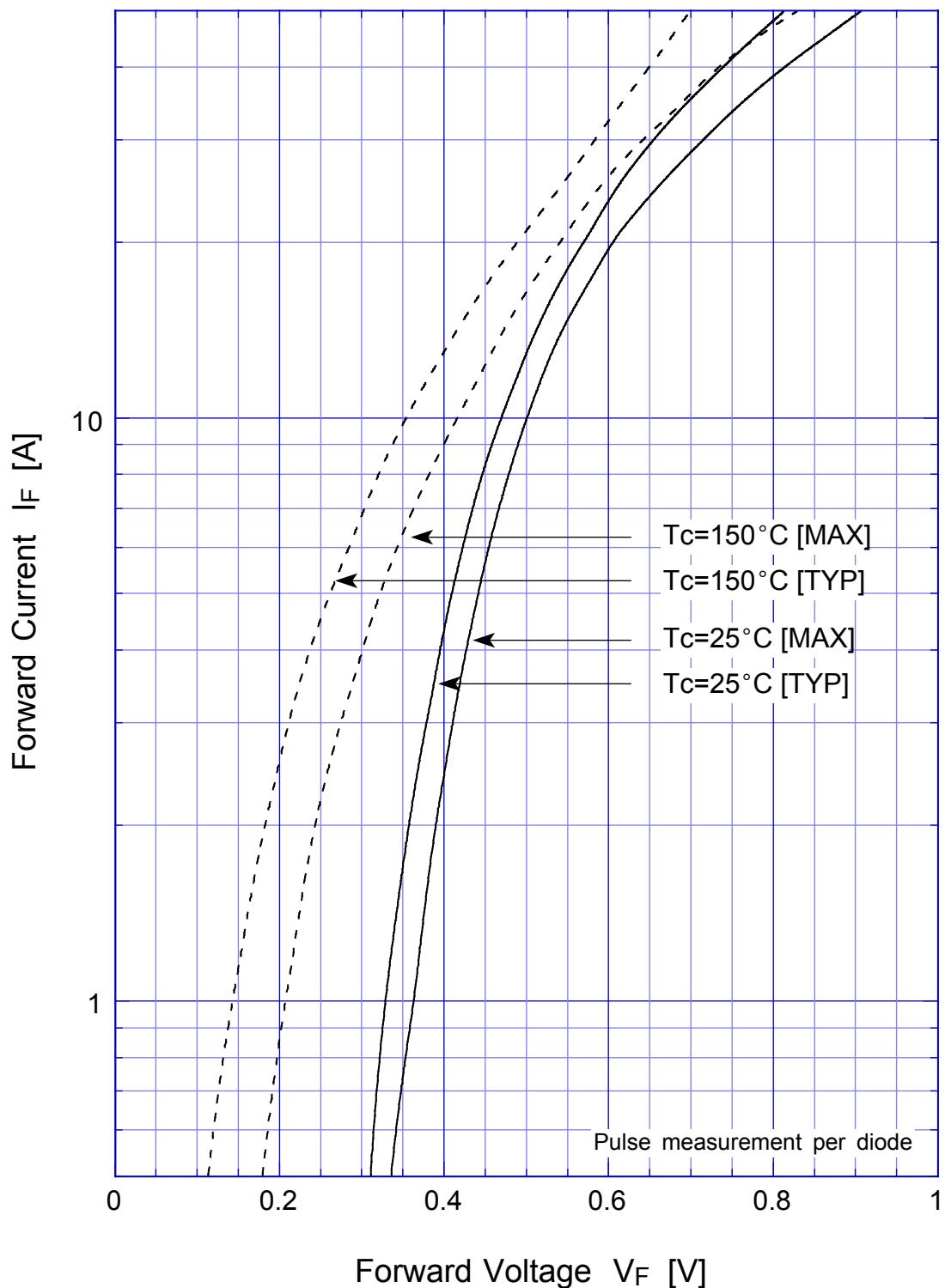
● Absolute Maximum Ratings (If not specified $T_c=25^\circ\text{C}$)

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T_{stg}		-40~150	$^\circ\text{C}$
Operating Junction Temperature	T_j		150	$^\circ\text{C}$
Maximum Reverse Voltage	V_{RM}		40	V
Repetitive Peak Surge Reverse Voltage	V_{RRSM}	Pulse width 0.5ms, duty 1/40	45	V
Average Rectified Forward Current	I_o	50Hz sine wave, R-load, Rating for each diode $I_o/2$, $T_c=112^\circ\text{C}$	30	A
Peak Surge Forward Current	I_{FSM}	50Hz sine wave, Non-repetitive 1 cycle peak value, $T_j=25^\circ\text{C}$	360	A
Repetitive Peak Surge Reverse Power	P_{RRSM}	Pulse width 10 μs , Rating of per diode, $T_j=25^\circ\text{C}$	1000	W

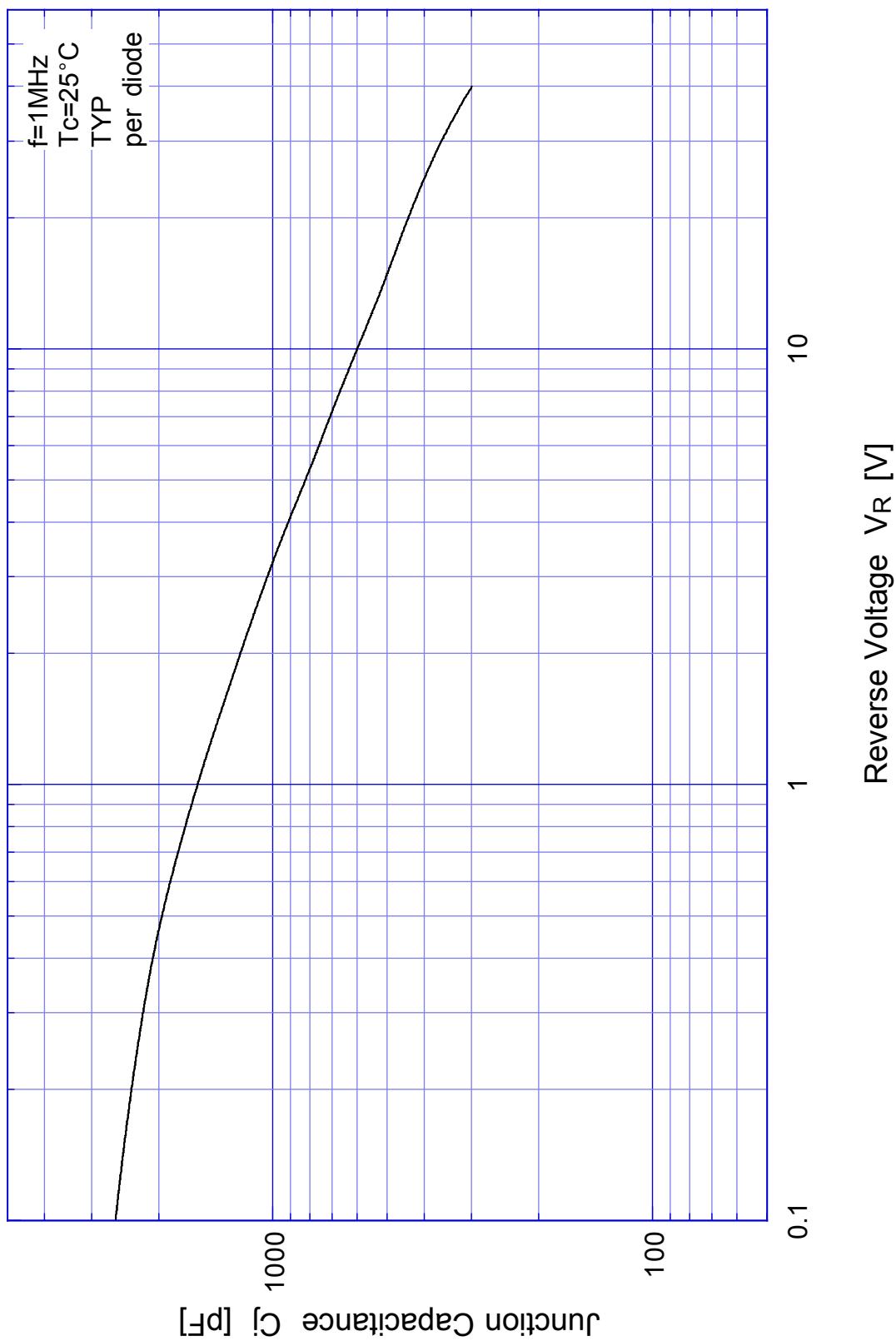
● Electrical Characteristics (If not specified $T_c=25^\circ\text{C}$)

Item	Symbol	Conditions	Ratings	Unit
Forward Voltage	V_F	$I_F=15\text{A}$, Pulse measurement, Rating of per diode	Max.0.55	V
Reverse Current	I_R	$V_R=V_{RM}$, Pulse measurement, Rating of per diode	Max.10	mA
Junction Capacitance	C_J	$f=1\text{MHz}$, $V_R=10\text{V}$, Rating of per diode	Typ.590	pF
Thermal Resistance	θ_{JC}	junction to case	Max.1.6	$^\circ\text{C}/\text{W}$

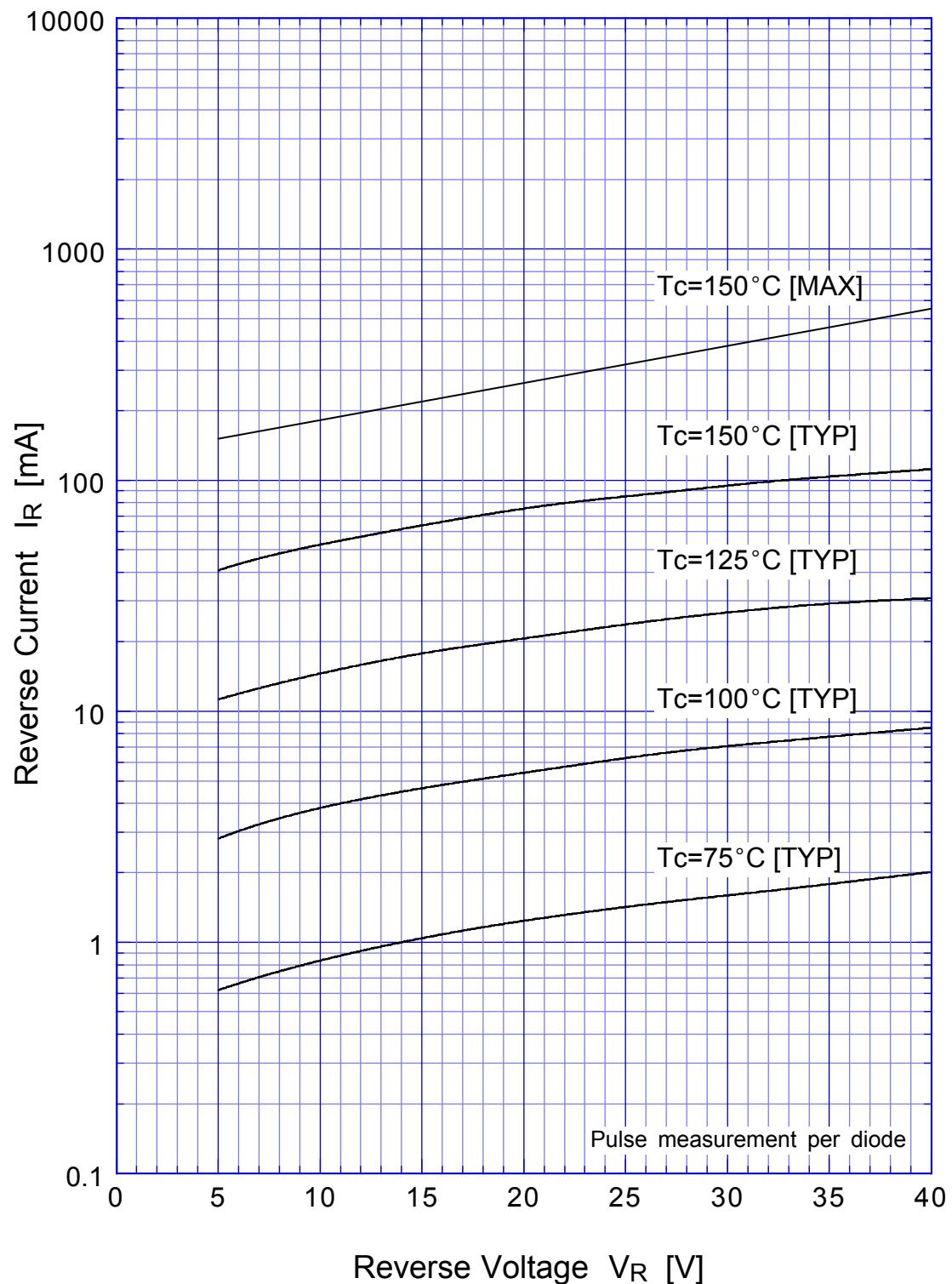
DF30SC4M Forward Voltage



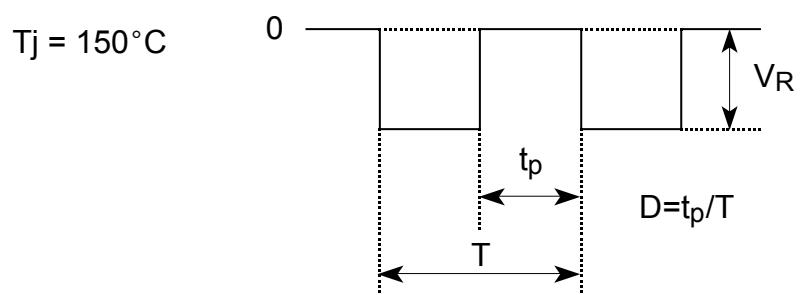
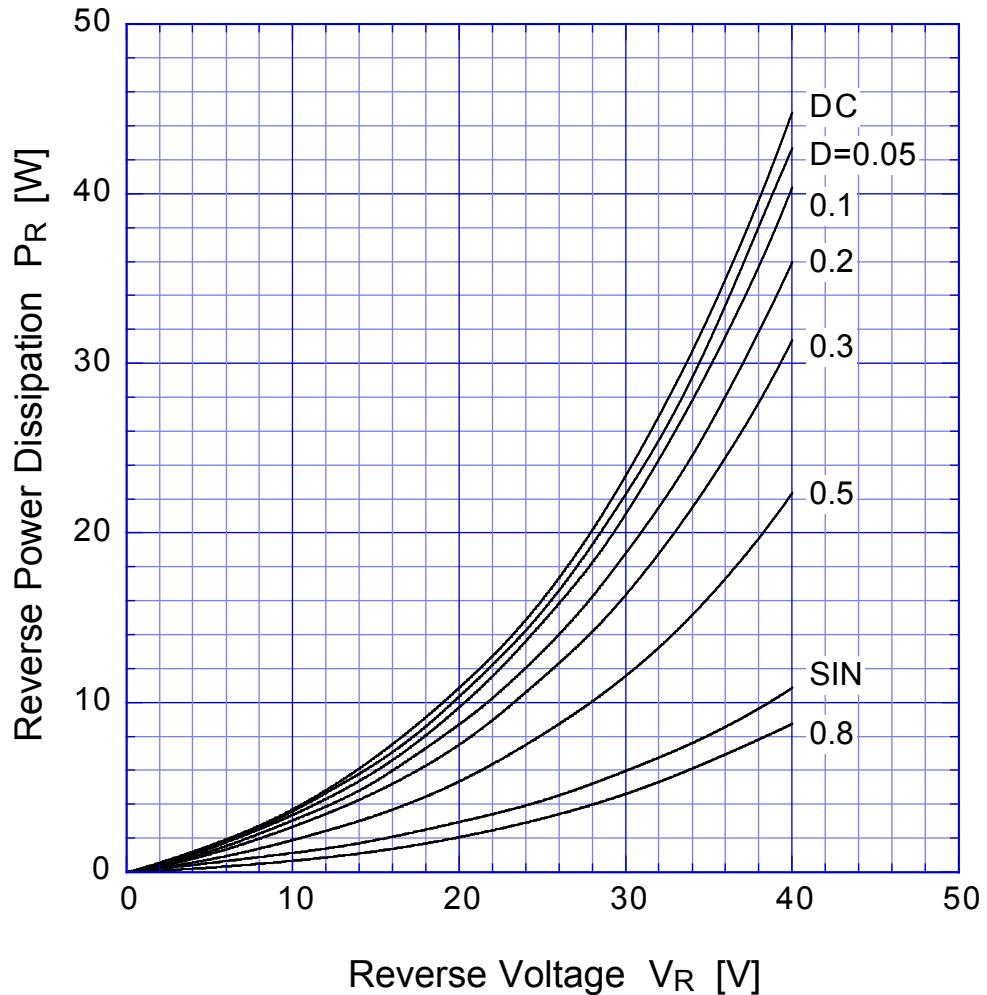
DF30SC4M Junction Capacitance



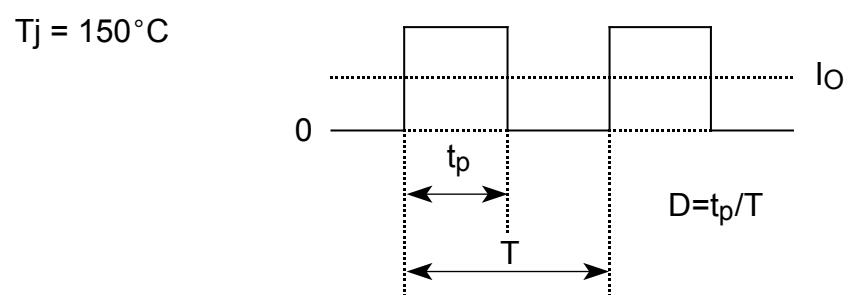
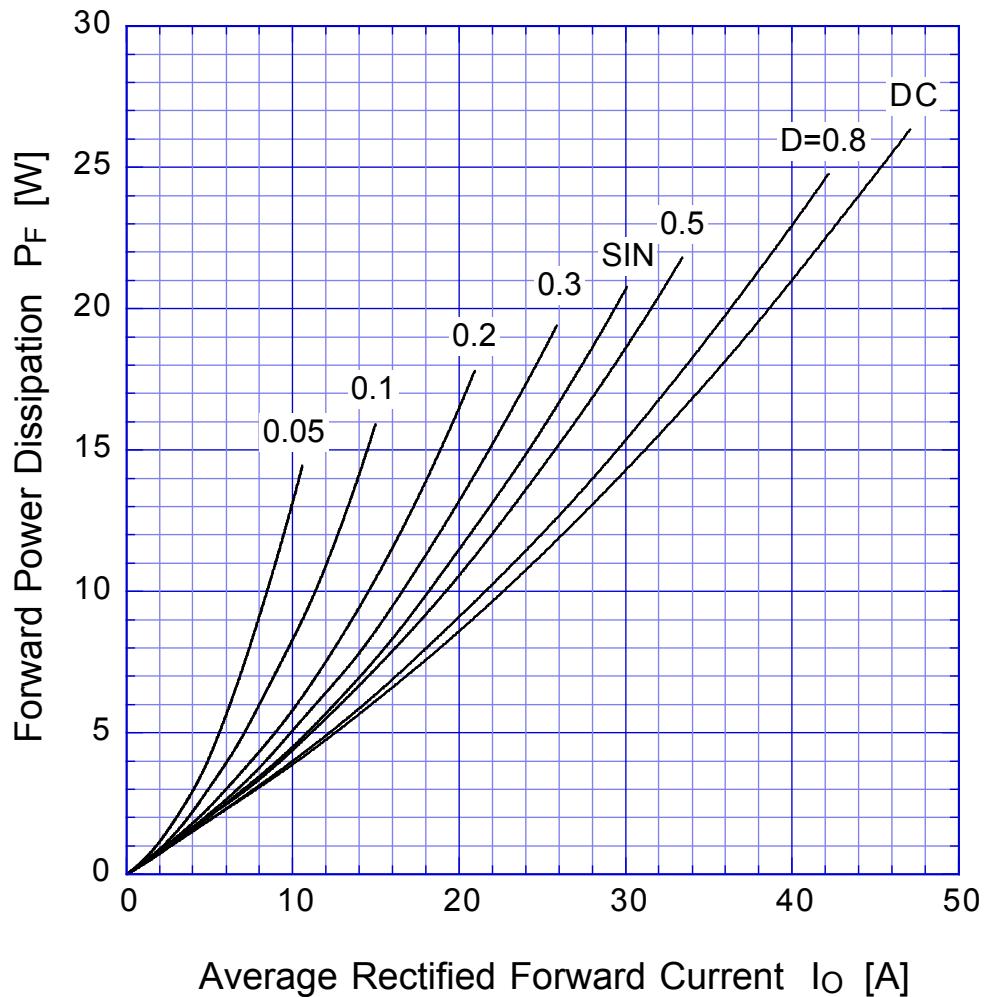
DF30SC4M Reverse Current

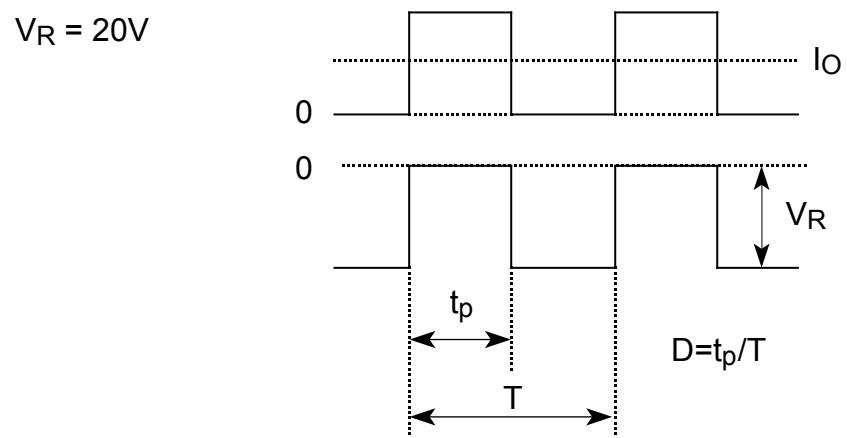
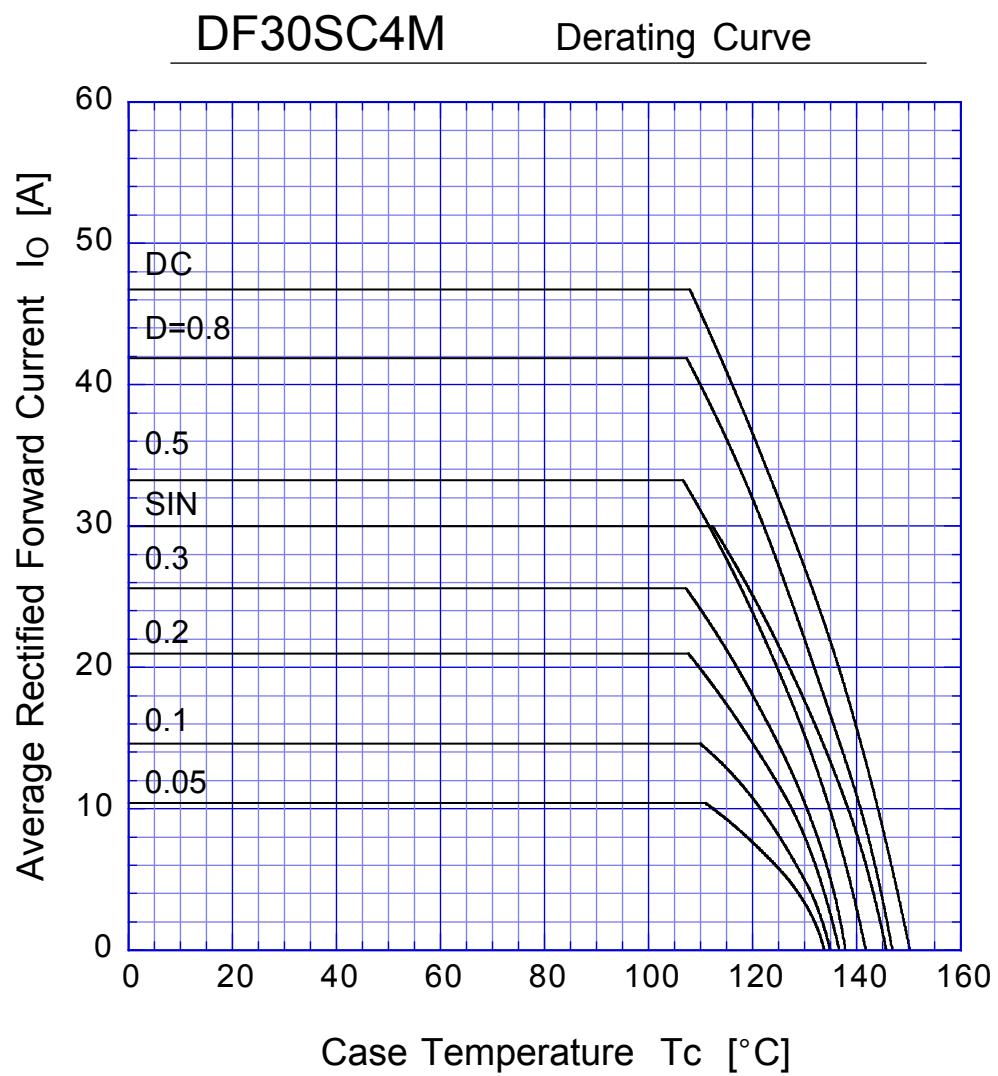


DF30SC4M Reverse Power Dissipation

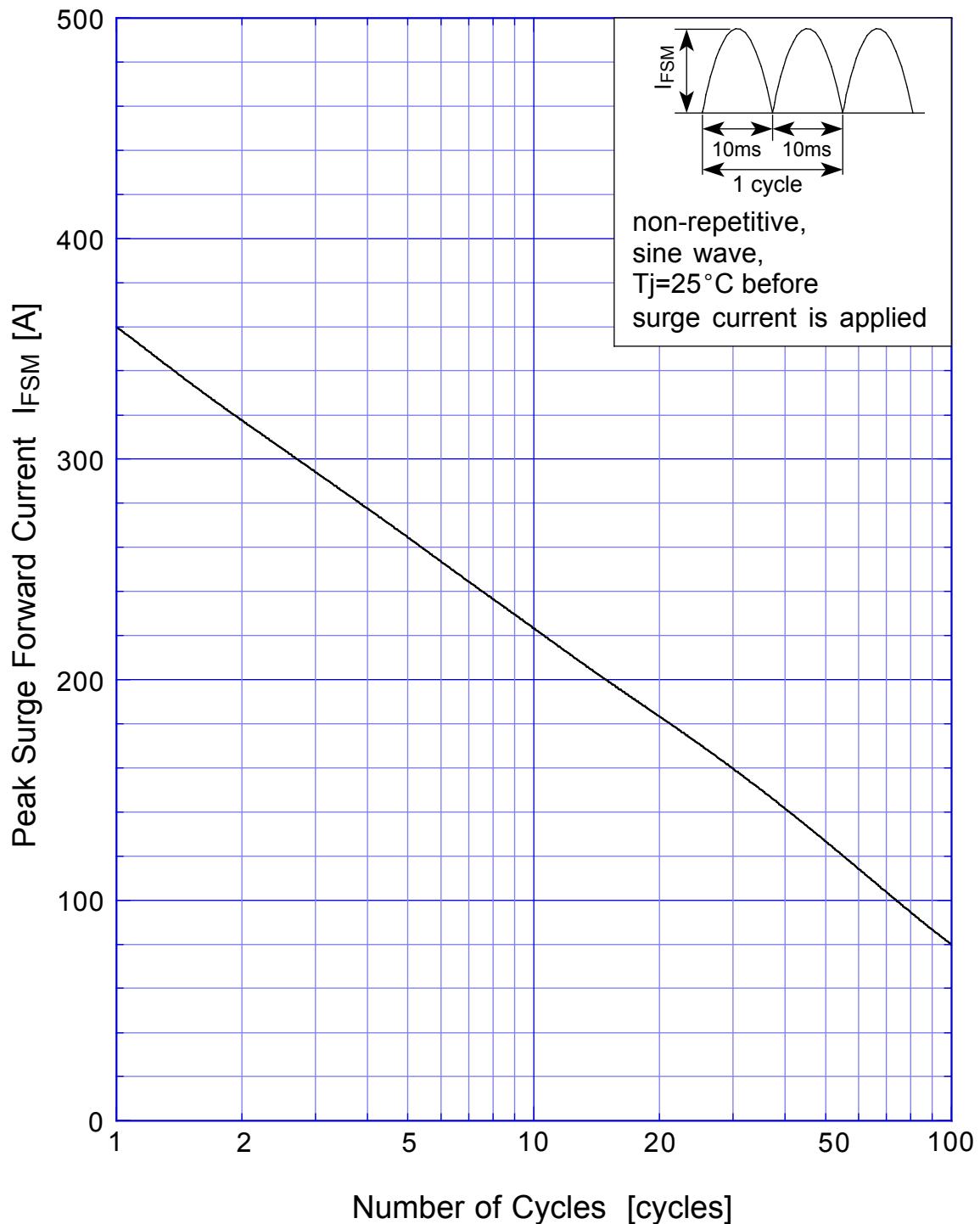


DF30SC4M Forward Power Dissipation

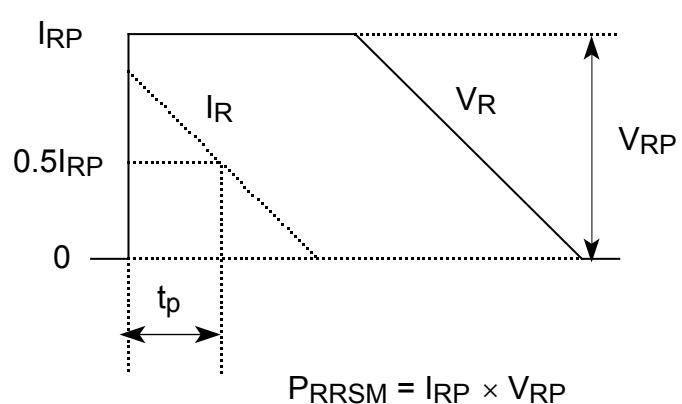
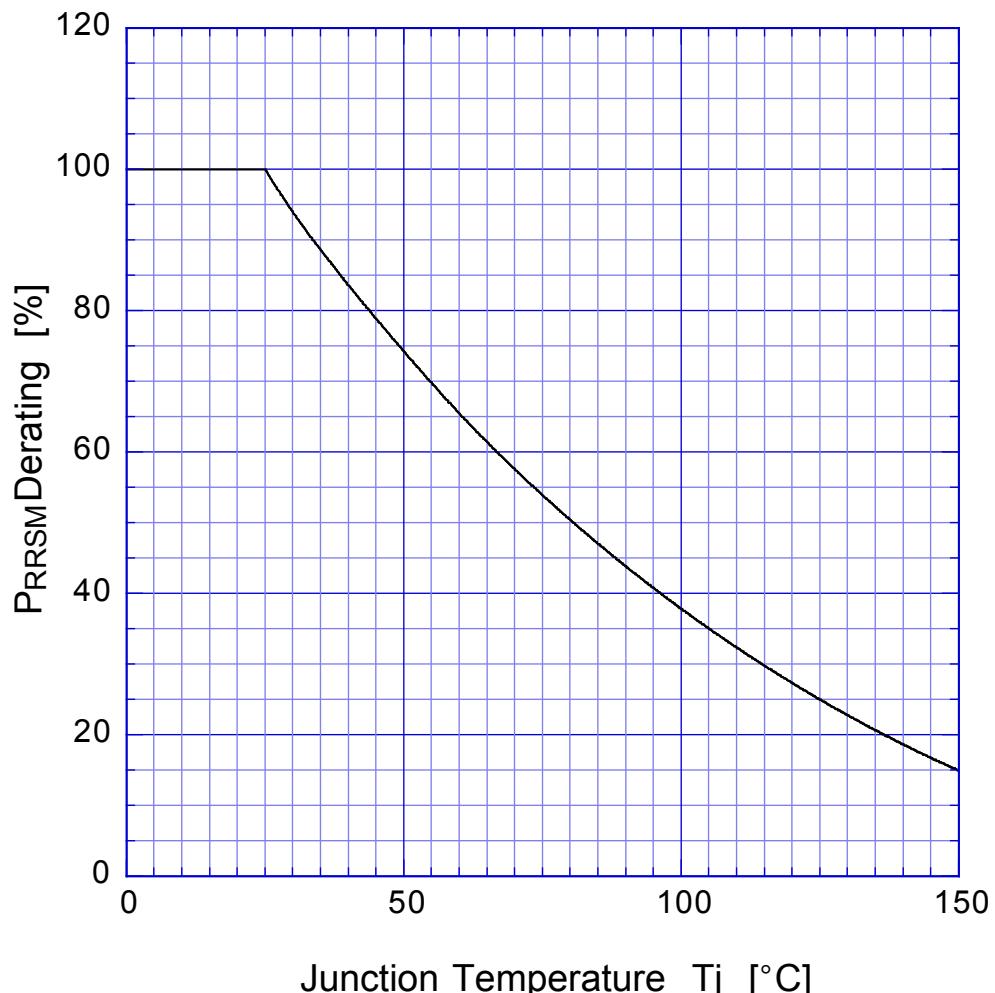




DF30SC4M Peak Surge Forward Capability



SBD Repetitive Surge Reverse Power Derating Curve



SBD Repetitive Surge Reverse Power Capability

